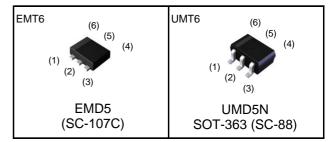
EMD5 / UMD5N

NPN + PNP Complex Digital Transistors (Bias Resistor Built-in Transistors)

<For DTr1(NPN)>

Parameter	Value
V _{CC}	50V
I _{C(MAX.)}	100mA
R ₁	47kΩ
R_2	47kΩ

Outline



Datasheet

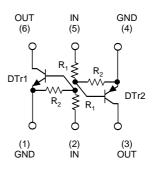
<For DTr2(PNP)>

Parameter	Value
V_{CC}	-50V
I _{C(MAX.)}	-100mA
R ₁	4.7kΩ
R_2	10kΩ

Features

- 1) Both the DTC144E chip and DTA143X chip in one package.
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Lead Free/RoHS Compliant.

•Inner circuit



Application

Inverter circuit, Interface circuit, Driver circuit

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMD5	EMT6	1616	T2R	180	8	8,000	D5
UMD5N	UMT6	2021	TR	180	8	3,000	D5

● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	DTr1(NPN)	DTr2(PNP)	Unit
Supply voltage	V _{CC}	50	-50	V
Input voltage	V _{IN}	-10 to +40	-20 to +7	V
Output current	Io	30	-100	mA
Collector current	I _{C(MAX.)} *1	100	-100	mA
Power dissipation	P _D *2	150 (Total)*3		mW
Junction temperature	T _j	150		°C
Range of storage temperature	T _{stg}	–55 to	°C	

●Electrical characteristics(Ta = 25°C) <For DTr1(NPN)>

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = 5V, I_{O} = 100 \mu A$	ı	1	0.5	V
input voitage	$V_{I(on)}$	$V_0 = 0.3V, I_0 = 2mA$	3.0	-	1	V
Output voltage	$V_{O(on)}$	$I_{O}/I_{I} = 10mA/0.5mA$	-	0.1	0.3	V
Input current	l ₁	V _I = 5V	-	-	0.18	mA
Output current	I _{O(off)}	$V_{CC} = 50V, V_I = 0V$	ı	-	0.5	μΑ
DC current gain	G _I	$V_O = 5V$, $I_O = 5mA$	68	-	-	-
Input resistance	R ₁	-	32.9	47	61.1	kΩ
Resistance ratio	R ₂ /R ₁	-	0.8	1	1.2	-
Transition frequency	f _T *1	$V_{CE} = 10V, I_{E} = -5mA$ f = 100MHz		250		MHz

•Electrical characteristics(Ta = 25°C) <For DTr2(PNP)>

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = -5V, I_{O} = -100 \mu A$	-	-	-0.3	V
input voitage	$V_{I(on)}$	$V_O = -0.3V, I_O = -20mA$	-2.5	-	-	V
Output voltage	$V_{O(on)}$	$I_{O}/I_{I} = -10\text{mA}/-0.5\text{mA}$	-	-0.1	-0.3	V
Input current	I _I	$V_1 = -5V$	-	-	-1.8	mA
Output current	I _{O(off)}	$V_{CC} = -50V, V_I = 0V$	-	-	-0.5	μΑ
DC current gain	G _I	$V_0 = -5V, I_0 = -10mA$	30	-	-	-
Input resistance	R ₁	-	3.29	4.7	6.11	kΩ
Resistance ratio	R ₂ /R ₁	-	1.7	2.1	2.6	-
Transition frequency	f _T *1	$V_{CE} = -10V, I_{E} = 5mA$ f = 100MHz	ı	250	-	MHz

^{*1} Characteristics of built-in transistor

^{*2} Each terminal mounted on a reference footprint

^{*3 120}mW per element must not be exceeded.

●Electrical characteristic curves (Ta = 25°C) <For DTr1(NPN)>

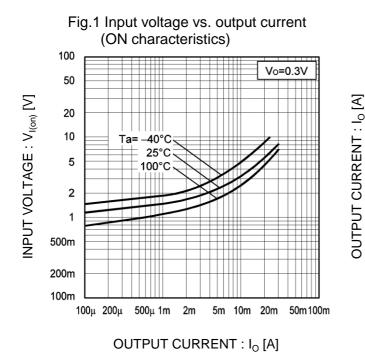


Fig.2 Output current vs. input voltage (OFF characteristics) 10m Vcc=5V 5m Ta=100°C 2m 25°C 1m -40°C 500μ 200μ 100μ 50μ 20μ 10μ 5μ 2μ 1μ 0 0.5 1.0 1.5 2.0 3.0 INPUT VOLTAGE : $V_{I(off)}[V]$

30 Ta=25°C 120μΑ OUTPUT CURRENT : Io [mA] 110μΑ 100μΑ 90μΑ 20 80μΑ 70μΑ 60μΑ 10 50μΑ 40μΑ 30μΑ 0 5 0 10

OUTPUT VOLTAGE: Vo [V]

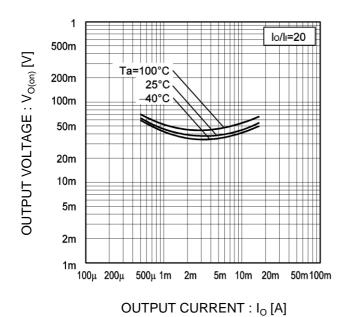
Fig.3 Output current vs. output voltage

1k V₀= 5V 500 Ta= 100°C CURRENT GAIN: G 200 25°C 40°C 100 50 20 10 5 2 $100\mu~200\mu$ 500μ 1m 5m 10m 20m 2m 50m 100m OUTPUT CURRENT: Io [A]

Fig.4 DC current gain vs. output current

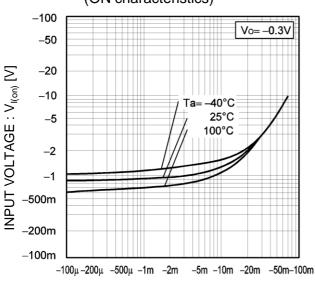
●Electrical characteristic curves (Ta = 25°C) <For DTr1(NPN)>

Fig.5 Output voltage vs. output current



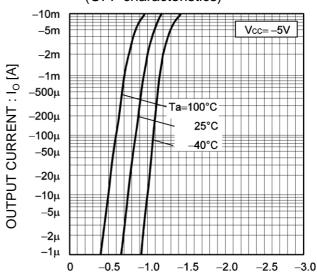
●Electrical characteristic curves (Ta = 25°C) <For DTr2(PNP)>

Fig.6 Input voltage vs. output current (ON characteristics)



OUTPUT CURRENT : I_O [A]

Fig.7 Output current vs. input voltage (OFF characteristics)



 $\mathsf{INPUT}\;\mathsf{VOLTAGE}:\mathsf{V}_{\mathsf{I}(\mathsf{off})}\![\mathsf{V}]$

●Electrical characteristic curves (Ta = 25°C) <For DTr2(PNP)>

Fig.8 Output current vs. output voltage

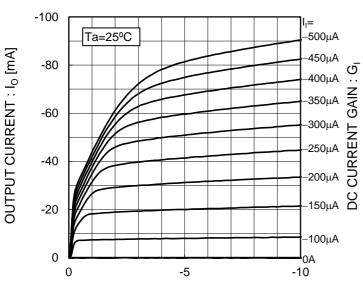
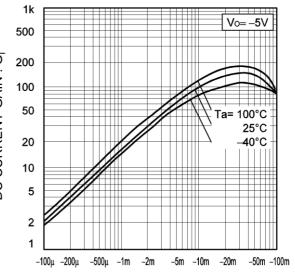


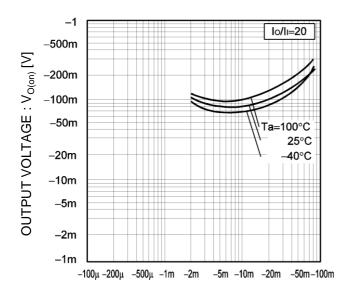
Fig.9 DC current gain vs. output current



OUTPUT CURRENT : Io [A]

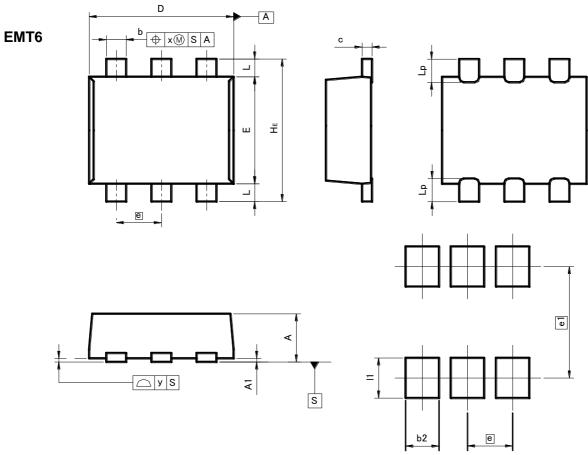
Fig.10 Output voltage vs. output current

OUTPUT VOLTAGE: Vo [V]



OUTPUT CURRENT : Io [A]

●Dimensions (Unit : mm)



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

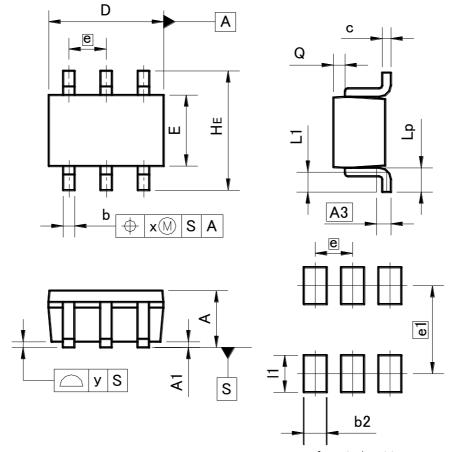
DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.45	0.55	0.018	0.022	
A1	0.00	0.10	0.000	0.004	
b	0.17	0.27	0.007	0.011	
С	0.08	0.18	0.003	0.007	
D	1.50	1.70	0.059	0.067	
Е	1.10	1.30	0.043	0.051	
е	0.	50	0.020		
HE	1.50	1.70	0.059	0.067	
L	0.10	0.30	0.004	0.012	
Lp	-	0.35	1	0.014	
х		0.10		0.004	
у	_	0.10	_	0.004	

DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
b2	-	0.37	-	0.015
e1	1.5	25	0.0)49
l1	_	0.45	_	0.018

Dimension in mm / inches

●Dimensions (Unit:mm)

UMT6



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.3	25	0.0	10
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	0.0	65	0.0	26
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
х	_	0.10		0.004
У	_	0.10		0.004

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
b2	-	0.40	-	0.016	
e1	1.55		0.0	061	
l1	_	0.65	_	0.026	

Dimension in mm / inches

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